PS9031

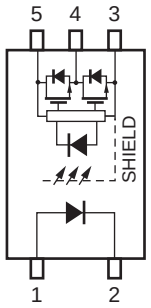
2.5 A OUTPUT CURRENT, HIGH CMR, IGBT GATE DRIVE,
5-PIN SOP (LSO5 WITH 8mm CREEPAGE DISTANCE) PHOTOCOUPLER

R08DS0131EJ0200
Rev.2.00
Mar 11, 2016

DESCRIPTION

The PS9031 is an optically coupled isolator containing a GaAlAs LED on the input side and a photodiode, a signal processing circuit and power MOSFETs on the output side on one chip.

PIN CONNECTION
(Top View)



1. Anode
2. Cathode
3. V_{EE}
4. V_O
5. V_{CC}

FEATURES

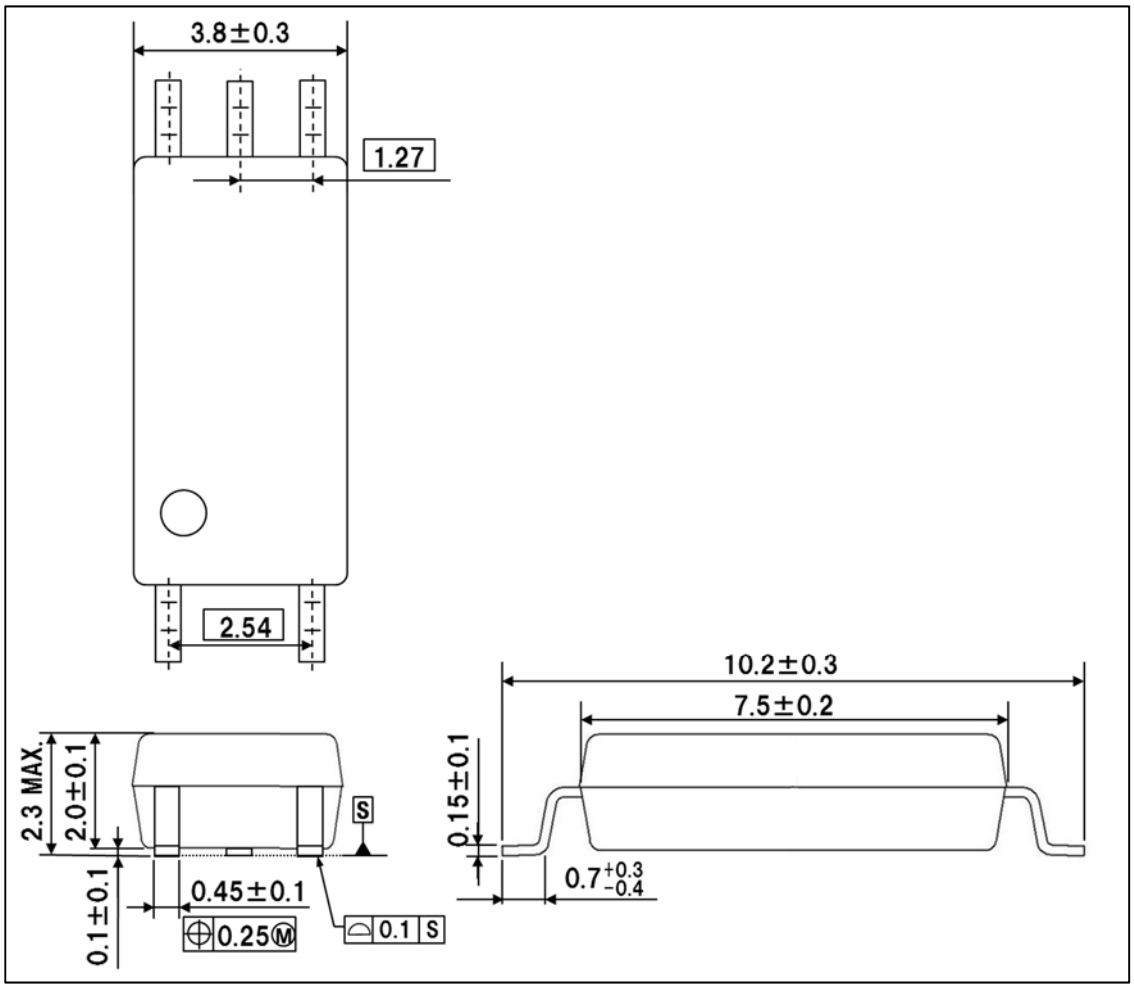
- Long creepage distance (8 mm MIN.)
- Large peak output current (2.5 A MAX., 2.0 A MIN.)
- High speed switching (t_{PLH}, t_{PHL} = 175 ns MAX.)
- UVLO (Under Voltage Lock Out) protection with hysteresis
- High common mode transient immunity (CM_H, CM_L = ±50 kV/μs MIN.)
- Operating Ambient Temperature (125 °C MAX.)
- Embossed tape product : PS9031-F3 : 3000 pcs/reel
- Pb-Free product
- Safety standards
  - UL approved: UL1577, Double protection
  - CSA approved: CA5A, CAN/CSA-C22.2 No.60065, CAN/CSA-C22.2 No.60950-1, Reinforced insulation
  - VDE approved: DIN EN 60747-5-5 (Option)

APPLICATIONS

- IGBT, Power MOS FET Gate Driver
- Industrial inverter
- AC Servo

Start of mass production
Oct.2015

PACKAGE DIMENSIONS (UNIT: mm)

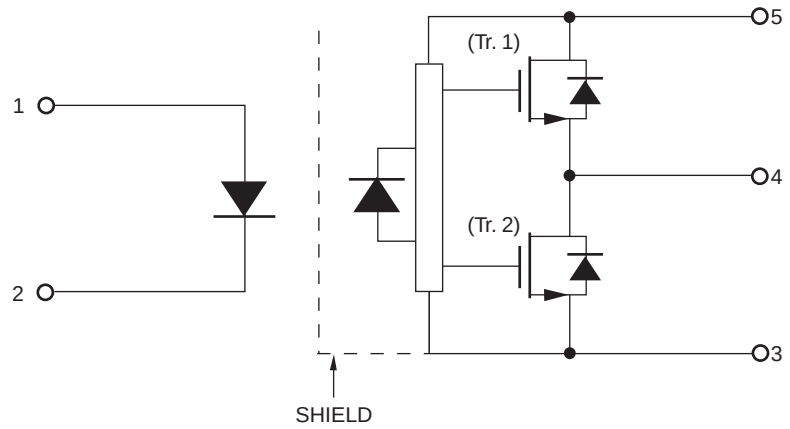


Weight: 0.119g (typ.)

PHOTOCOUPLER CONSTRUCTION

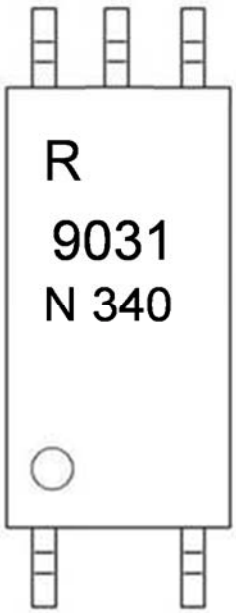
Parameter	MIN.
Air Distance	8.0 mm
Outer Creepage Distance	8.0 mm
Isolation Distance	0.15 mm

BLOCK DIAGRAM



Input	LED	Tr. 1	Tr. 2	Output
H	ON	ON	OFF	H
L	OFF	OFF	ON	L

MARKING EXAMPLE



R		An initial of “Renesas”
9031		Product Part Number
○		No.1 pin Mark, Anode Mark
N340	N	Rank Code
	340	Assembly Lot
	3	Last one-digit of Assembly Year
	40	Weekly Serial Code

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS9031	PS9031-Y-AX	Pb-Free and Halogen Free (Ni/Pd/Au)	20 pcs (Tape 20 pcs cut)	Standard products (UL,CSA approved)	PS9031
PS9031-F3	PS9031-Y-F3-AX		Embossed Tape 3 000 pcs/reel		
PS9031-V	PS9031-Y-V-AX		20 pcs (Tape 20 pcs cut)	UL,CSA approved DIN EN 60747-5-5 (VDE 0884-5): 2011-11 approved (Option)	
PS9031-V-F3	PS9031-Y-V-F3-AX		Embossed Tape 3 000 pcs/reel		

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current	I_F	25	mA
	Peak Transient Forward Current (Pulse Width < 1 μs)	$I_{F\ (TRAN)}$	1.0	A
	Reverse Voltage	V_R	5	V
	Power Dissipation *1	P_D	45	mW
Detector	High Level Peak Output Current *2	$I_{OH\ (PEAK)}$	2.5	A
	Low Level Peak Output Current *2	$I_{OL\ (PEAK)}$	2.5	A
	Supply Voltage	(V_{CC} – V_{EE})	0 to 35	V
	Output Voltage	V_O	0 to V_{CC}	V
	Power Dissipation *3	P_C	250	mW
Isolation Voltage *4		BV	5 000	Vr.m.s.
Operating Frequency		f	200	kHz
Operating Ambient Temperature		T_A	–40 to +125	°C
Storage Temperature		T_{stg}	–55 to +150	°C

Notes: *1. Reduced to 1.2 mW/°C at T_A = 110°C or more.
*2. Maximum pulse width = 10 μs, Maximum duty cycle = 0.2%
*3. Reduced to 3.9 mW/°C at T_A = 90°C or more.
*4. AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output.
Pins 1-2 shorted together, 3-5 shorted together.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	(V_{CC} – V_{EE})	15		30	V
Forward Current (ON)	$I_{F\ (ON)}$	8	10	12	mA
Forward Voltage (OFF)	$V_{F\ (OFF)}$	–2		0.8	V
Operating Ambient Temperature	T_A	–40		125	°C

ELECTRICAL CHARACTERISTICS

(at RECOMMENDED OPERATING CONDITIONS, V_{EE}=GND, unless otherwise Specified)

Parameter		Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	V_F	I_F = 10 mA, T_A = 25°C	1.35	1.56	1.75	V
	Reverse Current	I_R	V_R = 3 V, T_A = 25°C			10	μA
	Input Capacitance	C_{IN}	f = 1 MHz, V_F = 0 V		30		pF
Detector	High Level Output Current	I_{OH}	V_O = (V_{CC} – 4 V) *2	0.5	2.2		A
			V_O = (V_{CC} – 15 V) *3	2.0			
	Low Level Output Current	I_{OL}	V_O = (V_{EE} + 2.5 V) *2	0.5	2.4		A
			V_O = (V_{EE} + 15 V) *3	2.0			
	High Level Output Voltage	V_{OH}	I_O = –100 mA *4	V_{CC} – 3.0	V_{CC} – 1.3		V
	Low Level Output Voltage	V_{OL}	I_O = 100 mA		0.2	0.5	V
	High Level Supply Current	I_{CCH}	V_O = Open, I_F = 10 mA		1.7	2.2	mA
	Low Level Supply Current	I_{CCL}	V_O = Open, V_F = 0 to 0.8V		1.7	2.2	mA
	UVLO Threshold	V_{UVLO+}	V_O > 5 V, I_F = 10 mA	10.8	12.3	13.4	V
		V_{UVLO-}		9.5	11.0	12.5	
	UVLO Hysteresis	$UVLO_{HYS}$	V_O > 5 V, I_F = 10 mA	0.4	1.3		V
Coupled	Threshold Input Current (L → H)	I_{FLH}	I_O = 0 mA, V_O > 5 V		1.7	4.0	mA
	Threshold Input Voltage (H → L)	V_{FHL}	I_O = 0 mA, V_O < 5 V	0.8			V

Notes: *1. Typical values at T_A = 25°C, V_{CC} – V_{EE} = 30 V.

*2. Maximum pulse width = 50 μs, Maximum duty cycle = 0.5%.

*3. Maximum pulse width = 10 μs, Maximum duty cycle = 0.2%.

*4. V_{OH} is measured with the DC load current in this testing (Maximum pulse width = 2 ms, Maximum duty cycle = 20%).

SWITCHING CHARACTERISTICS

(at RECOMMENDED OPERATING CONDITIONS, V_{EE}=GND, unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Propagation Delay Time (L → H)	t_{PLH}	R_g = 10 Ω, C_g = 10 nF,		80	175	ns
Propagation Delay Time (H → L)	t_{PHL}	f = 10 kHz,		105	175	ns
Pulse Width Distortion (PWD)	$\lvert t_{PHL}–t_{PLH}\rvert$	Duty Cycle = 50%,		25	75	ns
Propagation Delay Time (Difference Between Any Two Products)	$t_{PHL}–t_{PLH}$	I_F = 10 mA	–90		90	ns
Rise Time	t_r			40		ns
Fall Time	t_f			40		ns
Common Mode Transient Immunity at High Level Output	$\lvert CM_H\rvert$	T_A = 25°C, I_F = 10 mA, V_{CC} = 30 V, V_{CM} = 1.5 kV	50			kV/μs
Common Mode Transient Immunity at Low Level Output	$\lvert CM_L\rvert$	T_A = 25°C, I_F = 0 mA, V_{CC} = 30 V, V_{CM} = 1.5 kV	50			kV/μs

Notes: *1. Typical values at T_A = 25°C, V_{CC}–V_{EE} = 30 V.

TEST CIRCUIT

Fig. 1 I_{OH} Test Circuit

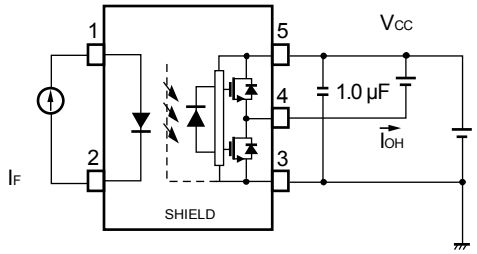


Fig. 2 I_{OL} Test Circuit

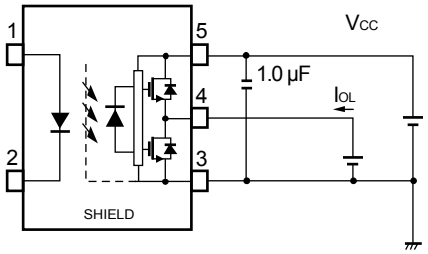


Fig. 3 V_{OH} Test Circuit

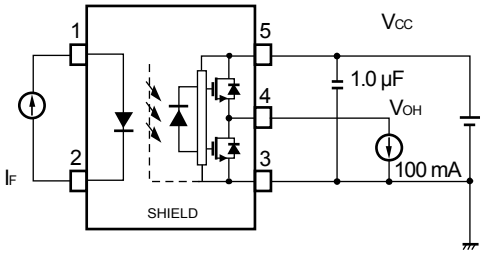


Fig. 4 V_{OL} Test Circuit

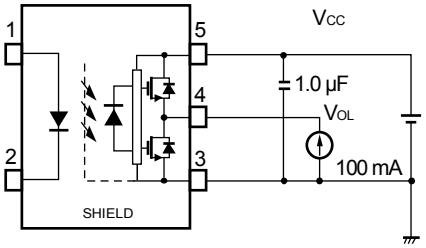


Fig. 5 I_{CCH}/I_{CCL} Test Circuit

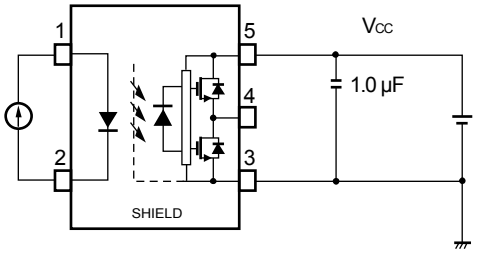


Fig. 6 UVLO Test Circuit

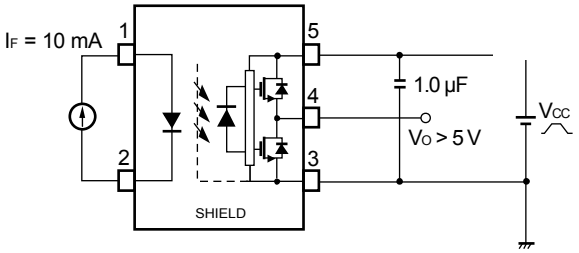


Fig. 7 I_{FLH} Test Circuit

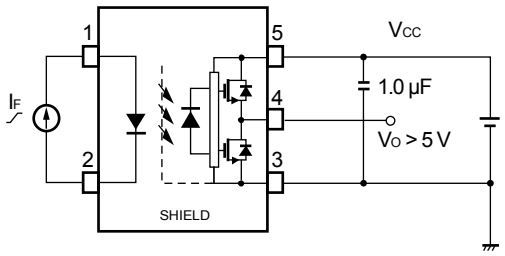
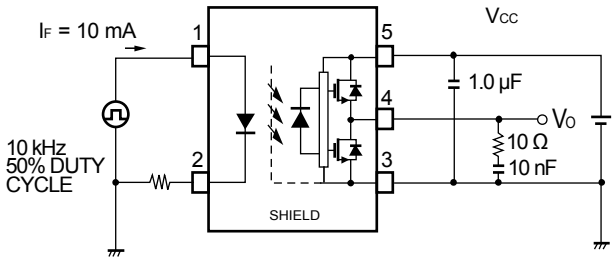


Fig. 8 t_{PLH}, t_{PHL}, t_r, t_f Test Circuit and Wave Forms



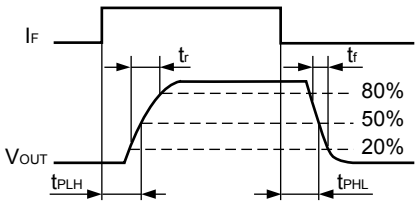
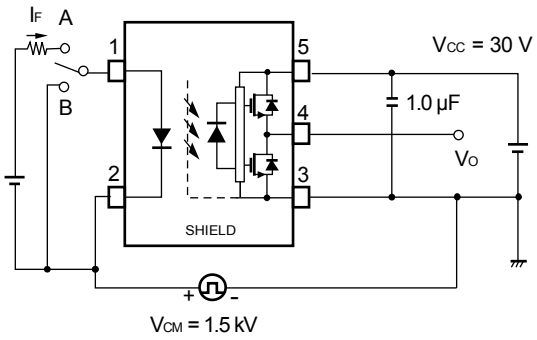
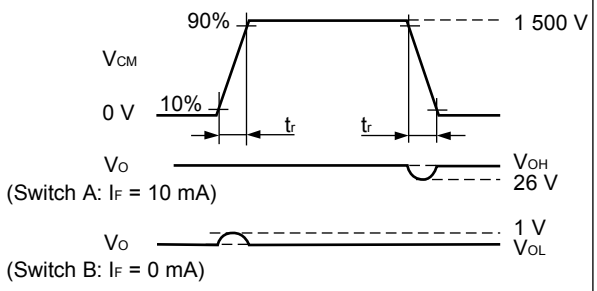


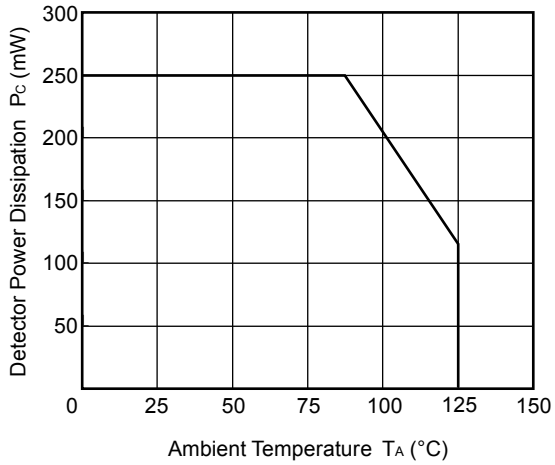
Fig. 9 CMR Test Circuit and Wave Forms



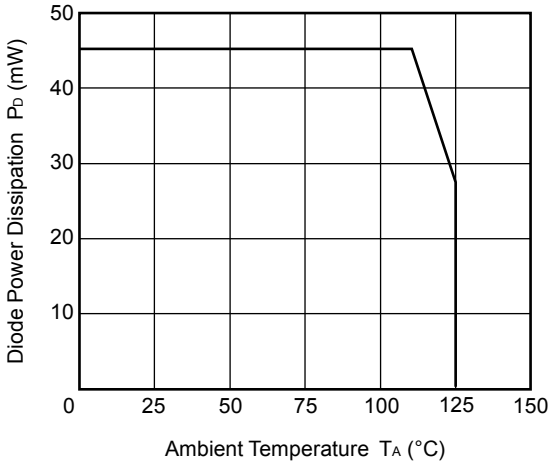


TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

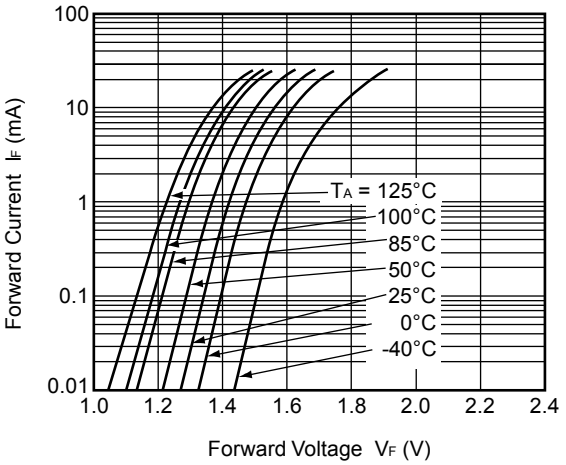
DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



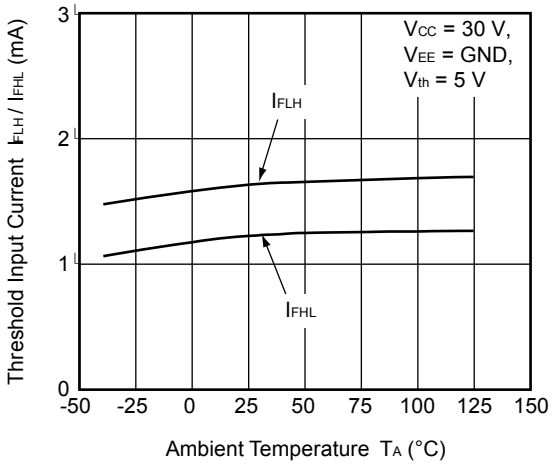
DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



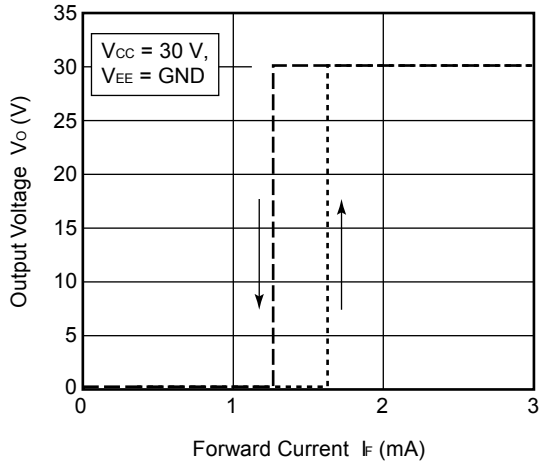
FORWARD CURRENT vs. FORWARD VOLTAGE



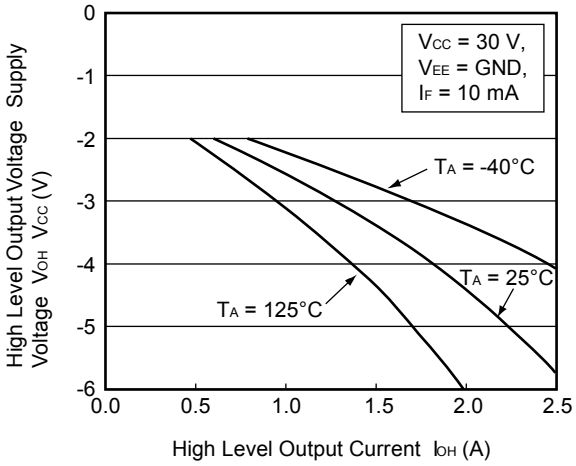
THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE



OUTPUT VOLTAGE vs. FORWARD CURRENT

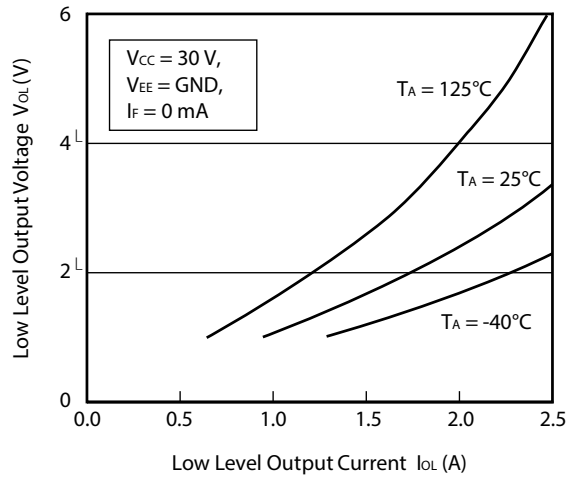


HIGH LEVEL OUTPUT VOLTAGE SUPPLY VOLTAGE vs. HIGH LEVEL OUTPUT CURRENT

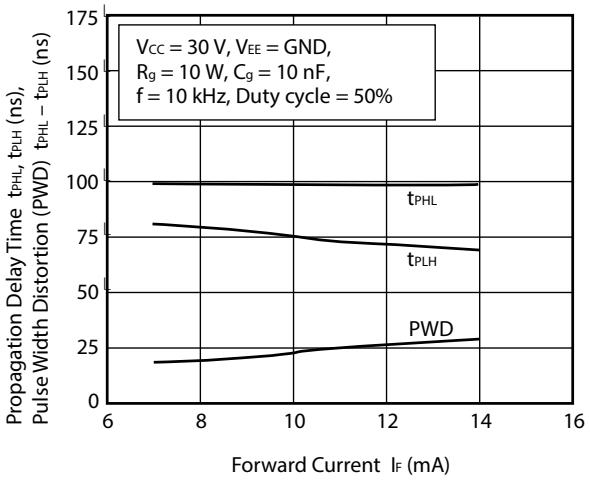


Remark The graphs indicate nominal characteristics.

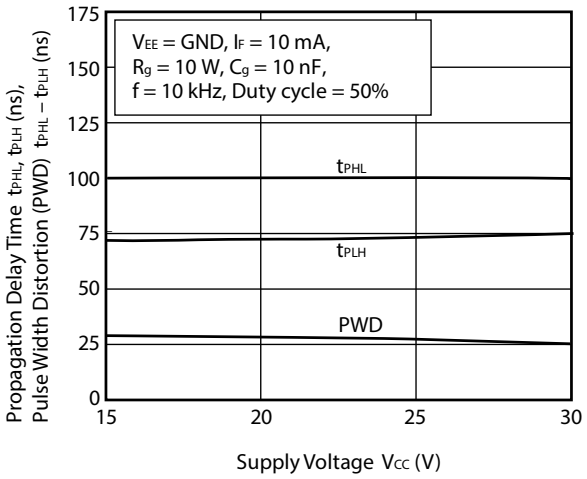
LOW LEVEL OUTPUT VOLTAGE vs.
LOW LEVEL OUTPUT CURRENT



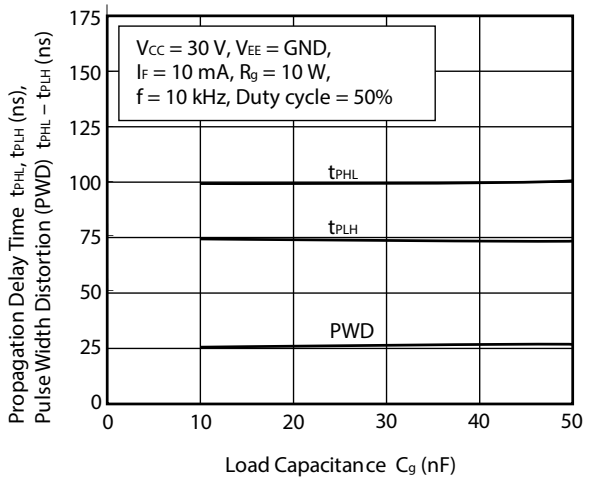
PROPAGATION DELAY TIME,
PULSE WIDTH DISTORTION
vs. FORWARD CURRENT



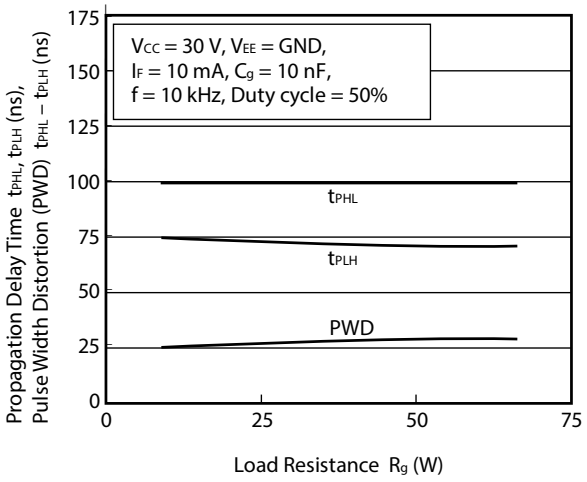
PROPAGATION DELAY TIME,
PULSE WIDTH DISTORTION
vs. SUPPLY VOLTAGE



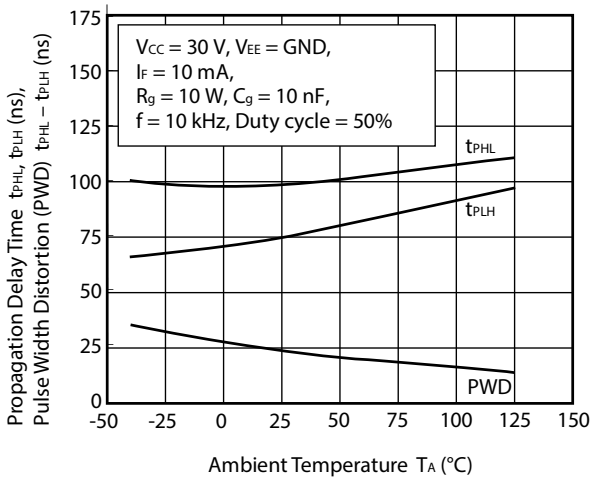
PROPAGATION DELAY TIME,
PULSE WIDTH DISTORTION
vs. LOAD CAPACITANCE



PROPAGATION DELAY TIME,
PULSE WIDTH DISTORTION
vs. LOAD RESISTANCE

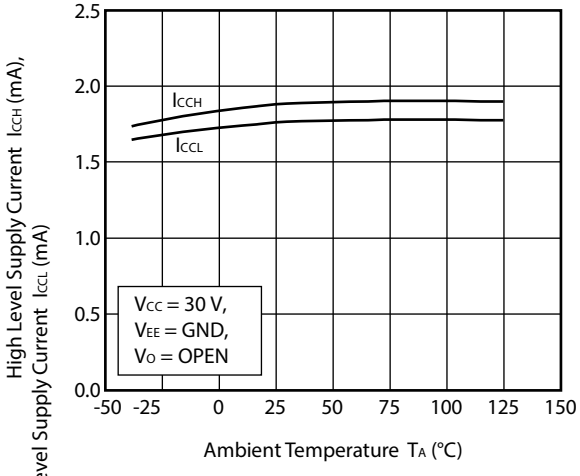


PROPAGATION DELAY TIME,
PULSE WIDTH DISTORTION
vs. AMBIENT TEMPERATURE

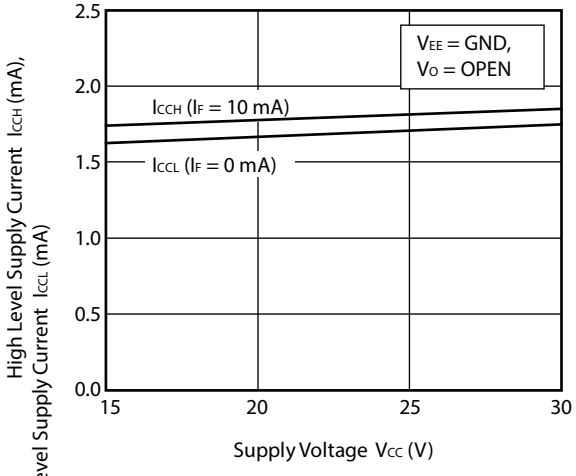


Remark The graphs indicate nominal characteristics.

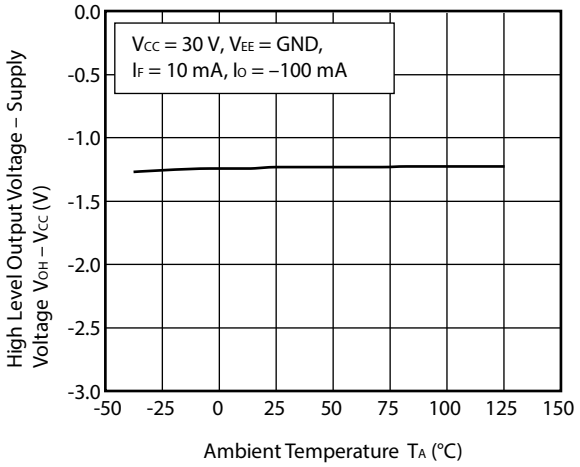
SUPPLY CURRENT vs.
AMBIENT TEMPERATURE



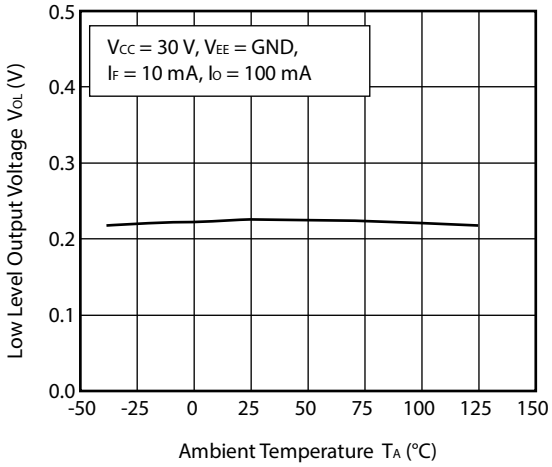
SUPPLY CURRENT vs.
SUPPLY VOLTAGE



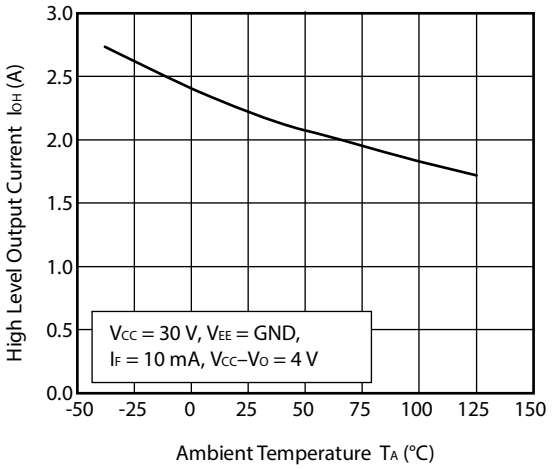
HIGH LEVEL OUTPUT VOLTAGE – SUPPLY
VOLTAGE vs. AMBIENT TEMPERATURE



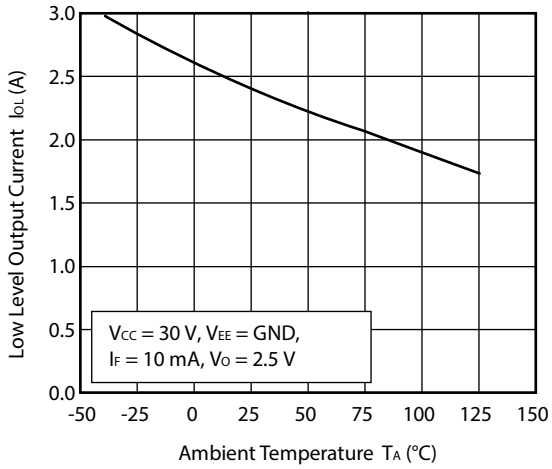
LOW LEVEL OUTPUT VOLTAGE vs.
AMBIENT TEMPERATURE



HIGH LEVEL OUTPUT CURRENT vs.
AMBIENT TEMPERATURE

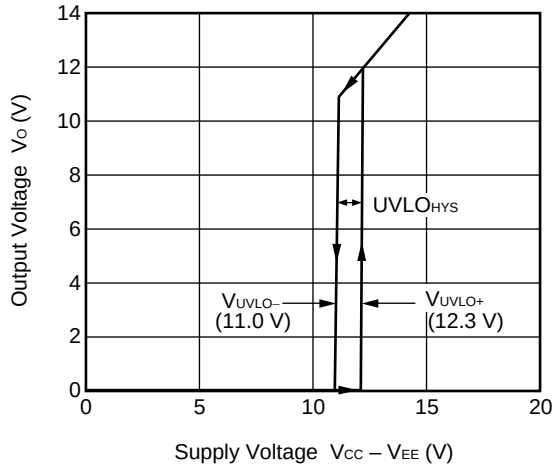


LOW LEVEL OUTPUT CURRENT vs.
AMBIENT TEMPERATURE



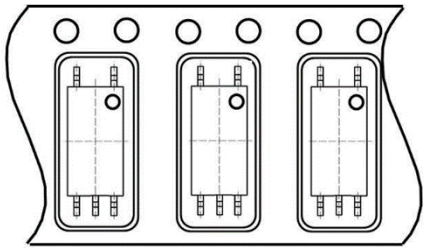
Remark The graphs indicate nominal characteristics.

OUTPUT VOLTAGE vs. SUPPLY VOLTAGE



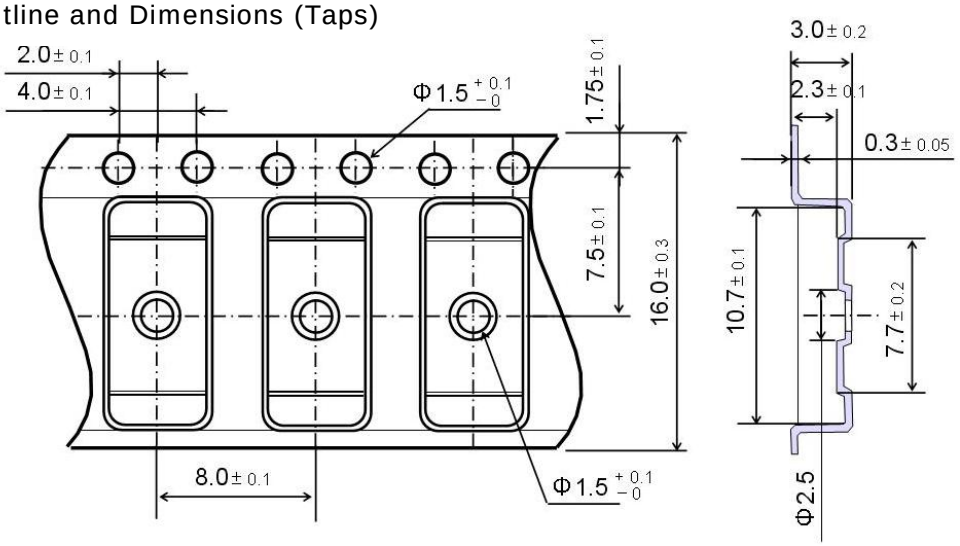
Remark The graphs indicate nominal characteristics.

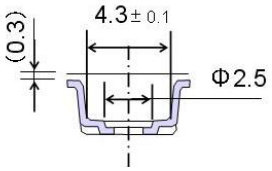
TAPING SPECIFICATIONS (UNIT: mm)



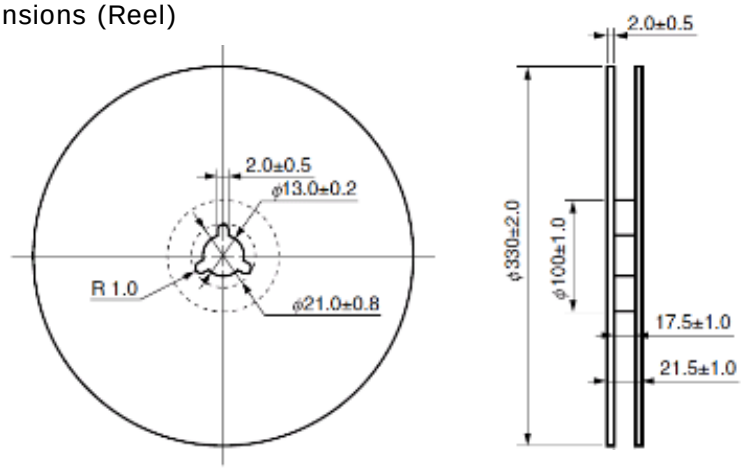
Tape Direction

Outline and Dimensions (Taps)



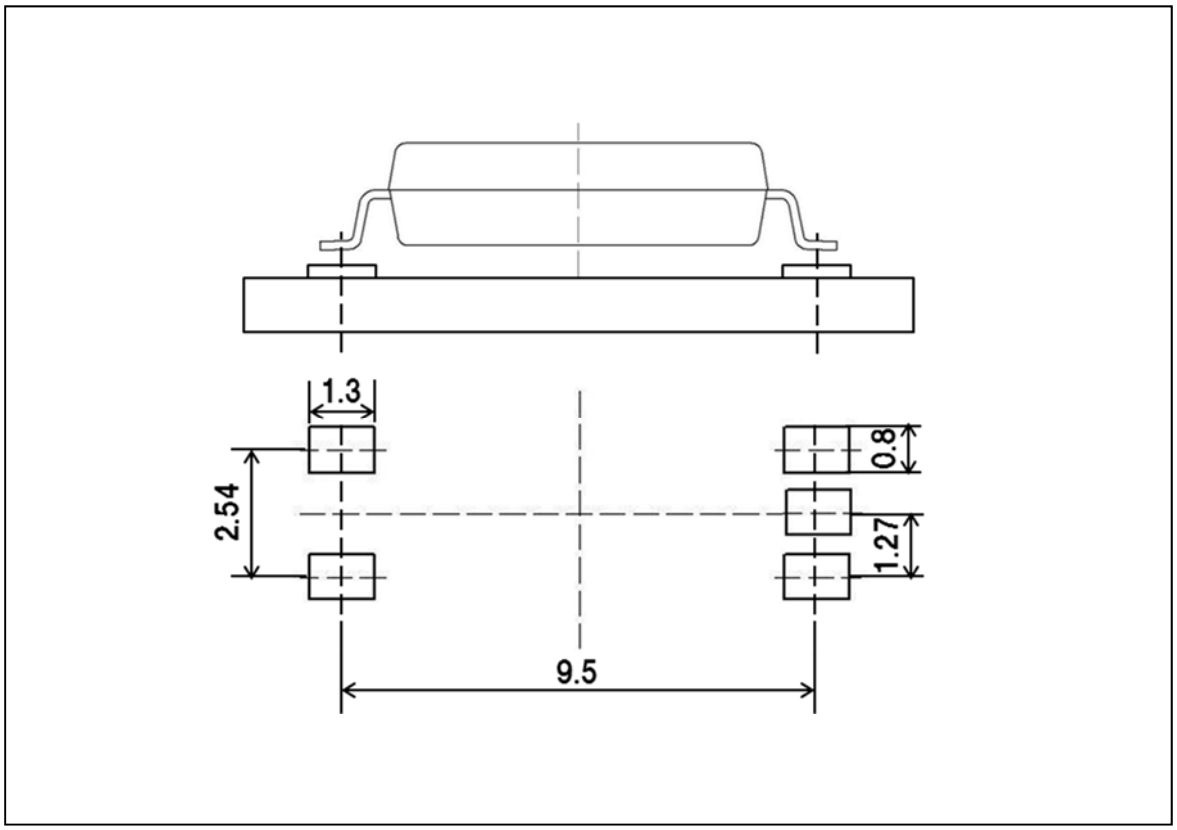


Outline and Dimensions (Reel)



Packing:3000 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

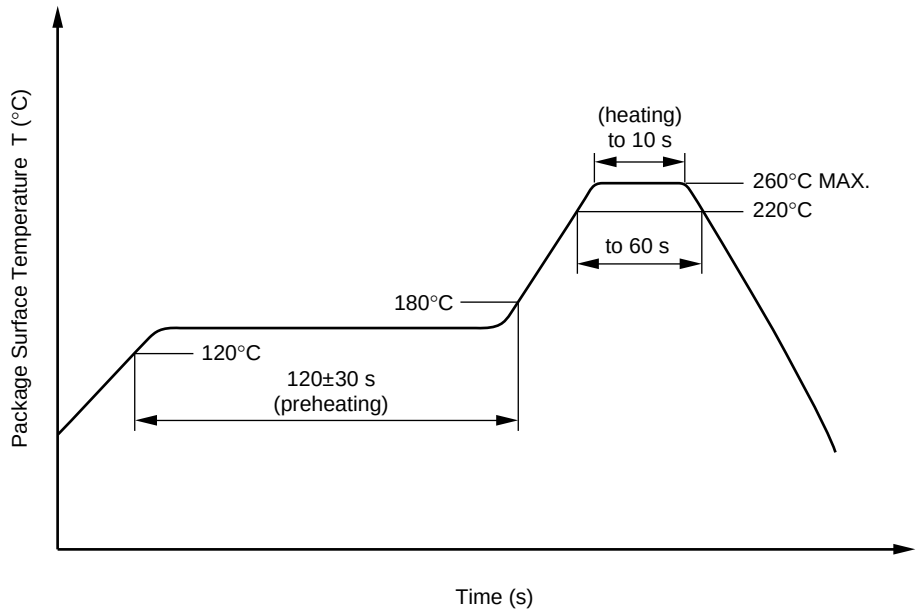
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature	260°C or below (package surface temperature)
• Time of peak reflow temperature	10 seconds or less
• Time of temperature higher than 220°C	60 seconds or less
• Time to preheat temperature from 120 to 180°C	120±30 s
• Number of reflows	Three
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature	260°C or below (molten solder temperature)
• Time	10 seconds or less
• Preheating conditions	120°C or below (package surface temperature)
• Number of times	One (Allowed to be dipped in solder including plastic mold portion.)
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

• Peak Temperature (lead part temperature)	350°C or below
• Time (each pins)	3 seconds or less
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

• Fluxes	Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

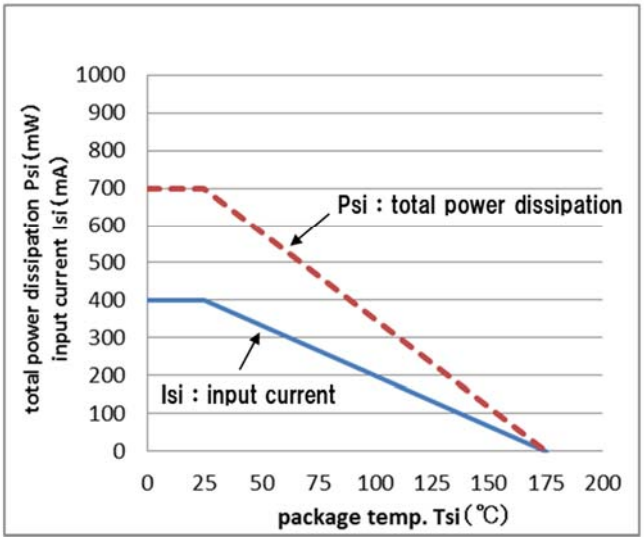
USAGE CAUTIONS

1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. Board designing
   (1) By-pass capacitor of more than 1.0 μF is used between VCC and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
   (2) When designing the printed wiring board, ensure that the pattern of the IGBT collectors/emitters is not too close to the input block pattern of the photocoupler.
   If the pattern is too close to the input block and coupling occurs, a sudden fluctuation in the voltage on the IGBT output side might affect the photocoupler's LED input, leading to malfunction or degradation of characteristics.
   (If the pattern needs to be close to the input block, to prevent the LED from lighting during the off state due to the abovementioned coupling, design the input-side circuit so that the bias of the LED is reversed, within the range of the recommended operating conditions, and be sure to thoroughly evaluate operation.)
3. Make sure the rise/fall time of the forward current is 0.5 μs or less.
4. In order to avoid malfunctions, make sure the rise/fall slope of the supply voltage is 3 V/μs or less.
5. Avoid storage at a high temperature and high humidity.

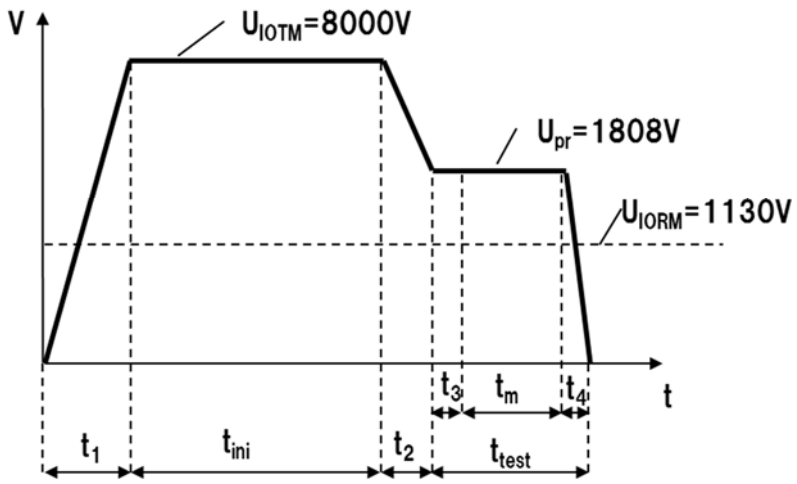
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) U_{pr} = 1.6 × $U_{IORM.}$, P_d < 5 pC	 U_{IORM} U_{pr}	 1 130 1 808	 V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) U_{pr} = 1.875 × $U_{IORM.}$, P_d < 5 pC	U_{pr}	2 119	V_{peak}
Highest permissible overvoltage	U_{IOTM}	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	400	
Material group (DIN EN 60664-1 VDE0110 Part 1)		II	
Storage temperature range	T_{stg}	–55 to +150	°C
Operating temperature range	T_A	–40 to +125	°C
Isolation resistance, minimum value V_{IO} = 500 V dc at T_A = 25°C V_{IO} = 500 V dc at T_A MAX. at least 100°C	 Ris MIN. Ris MIN.	 10^{12} 10^{11}	 Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F, Psi = 0) Power (output or total power dissipation) Isolation resistance V_{IO} = 500 V dc at T_A = Tsi	 Tsi Isi Psi Ris MIN.	 175 400 700 10^9	 °C mA mW Ω

Dependence of maximum safety ratings with package temperature

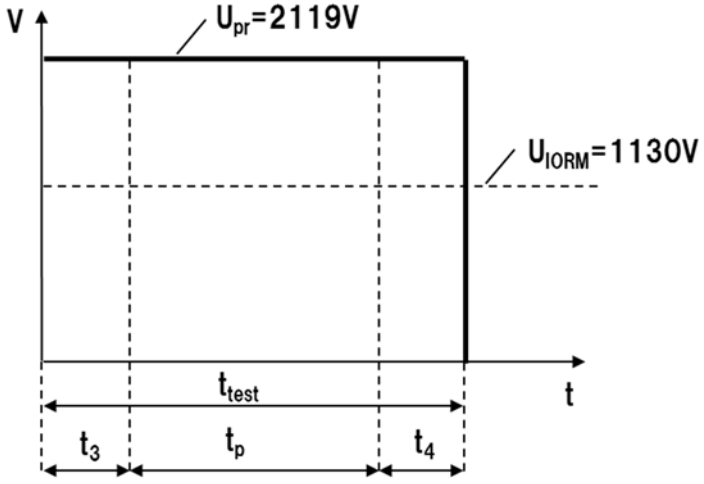


Method A Destructive Test, Type and Sample test



t_1,t_2=1 to 10 sec
t_3,t_4=1 sec
$t_{m\ (PARTIAL\ DISCHARGE)}$=10 sec
t_{test}=12 sec
t_{ini}=60 sec

Method b Non-destructive Test, 100% Production Test



t_3,t_4=0.1 sec
$t_{p\ (PARTIAL\ DISCHARGE)}$=1.0 sec
t_{test}=1.2 sec

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